

Receipt date: 12/22/2008

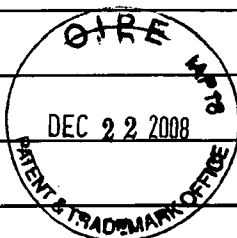
INFORMATION DISCLOSURE CITATION

(Use several sheets if necessary)

Docket Number (Optional)
3836.001Application Number
10/554,136Applicant(s)
Hiroshi KAWAZOEFiling Date
May 12, 2006Group Art Unit
2811

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE



U.S. PATENT APPLICATION PUBLICATIONS

*EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

FOREIGN PATENT DOCUMENTS

	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
							YES	NO

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

/H.H./		PARK et al., "p-type ZnSe by nitrogen atom beam doping during molecular beam epitaxial growth" Applied Physics Letters, Vol. 57, No. 20, 12 November 1990, pp. 2127- 2129

EXAMINER

/Hsin Yi Hsieh/

DATE CONSIDERED

03/28/2009

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.